

## 3ch Laser Diode Driver

### ■GENERAL DESCRIPTION

**NJW4702** is a laser diode driver for the operation of a grounded laser diode for CD-R and CD-RW drivers.

It includes three channels current amplifiers for three different optical power levels. Reference inputs are voltage input, and voltage control is possible without external resistors. An on-chip RF oscillator is provided to reduce laser mode noise during read mode. Oscillation frequency and oscillation amplitude are defined by two external resistors.

### ■PACKAGE OUTLINE

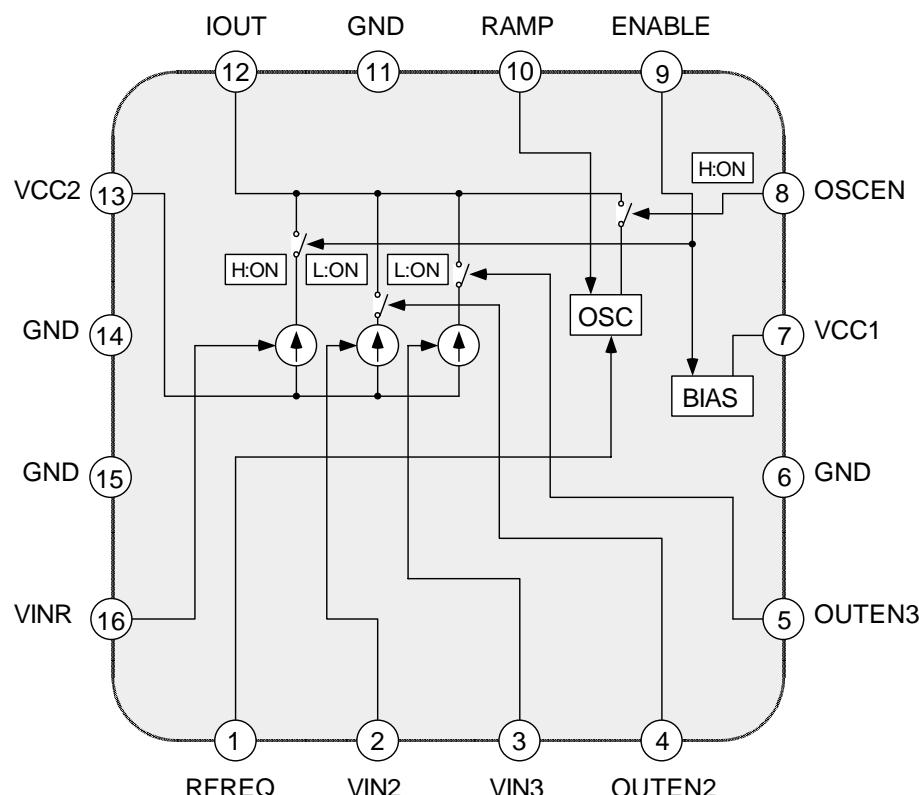


NJW4702SE8

### ■FEATURES

- Operating Voltage 4.5V to 5.5V
- On-chip RF Oscillator 200MHz to 500MHz
- Rise-time/Fall-time 1.0ns typ.
- Maximum Output Current 250mA typ.
- Bi-CMOS Technology
- Package Outline PCSP16(3.5mm 0.65mm pitch)

### ■BLOCK DIAGRAM



# NJW4702

## ■ABSOLUTE MAXIMUM RATING (Ta=25°C)

PARAMETERS	SYMBOL	RATINGS	UNIT
Supply Voltage	V <sup>+</sup>	6.0	V
Power Dissipation	P <sub>D</sub>	860 *	mW
Operating Temperature Range	T <sub>opr</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +125	°C

\*EIA/JEDEC STANDARD Test Board(76.2x114.3x1.6mm,4layers,FR-4)mounting

## ■RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETERS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V <sub>opr</sub>		4.5	5.0	5.5	V

## ■ELECTRICAL CHARACTERISTICS

### ●DC CHARACTERISTICS(V<sub>cc</sub>=5.0V,ENABLE=H,OUTEN=H,OSCEN=L, H:5V,L:GND,2V to I<sub>out</sub>, Ta=25°C unless otherwise specified)

PARAMETERS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current 1	I <sub>cc1</sub>	ENABLE≤0.5V	-	0	10	μA
Supply Current 2	I <sub>cc2</sub>	VINR/2/3=0V	-	5	7	mA
Supply Current 3	I <sub>cc3</sub>	OSCEN=H,RAMP=1kΩ,RFREQ=3.6kΩ	-	55	75	mA
Supply Current 4	I <sub>cc4</sub>	VINR=0V,VIN2=0.3V,VIN3=0.3V	-	20	30	mA
Supply Current 5	I <sub>cc5</sub>	VINR=0.8V,VIN2/3=0.3V	-	80	110	mA
High Level Input Voltage	V <sub>IH</sub>		3.5	-	-	V
Low level Input Voltage	V <sub>IL</sub>		-	-	1.5	V
High Level Input Current	I <sub>IIH</sub>		-	-	100	μA
Low Level Input Current	I <sub>IIL</sub>		-100	-	-	μA
Shutdown Voltage	V <sub>shut</sub>	VINR=0.8V,VIN2/3=0.3V, OUTEN=L,OSCEN=H,V <sub>cc</sub> at I <sub>cc</sub> ≤1mA	3.4	-	3.7	V

### ●Laser Amp DC CHARACTERISTICS

(V<sub>cc</sub>=5.0V,ENABLE=H,OUTEN=H,OSCEN=L, H:5V,L:GND,2V to I<sub>out</sub>, Ta=25°C unless otherwise specified)

PARAMETERS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Convert Gain 1	G <sub>i1</sub>	CHR *1	35	50	65	mA/V
Current Convert Gain 2	G <sub>i2</sub>	CH2/3 *1	80	120	160	mA/V
Output Offset Current	I <sub>os</sub>	CHR/2/3 *1	-2	-	+8	mA
Output Current Linearity	I <sub>lin</sub>	CHR/2/3 *1	-3	-	+3	%
Input Voltage Range	V <sub>refR</sub>	CHR/2/3	0	-	5	V
Maximum Output Current 1	I <sub>omax1</sub>	CHR	100	150	-	mA
Maximum Output Current 2	I <sub>omax2</sub>	CH2/3	200	250	-	mA
I <sub>out</sub> Series Resistance	R <sub>o</sub>		-	6	-	Ω
Input Resistance	R <sub>in</sub>		6	9	12	kΩ
Output OFF Current 1	I <sub>off1</sub>	OUTEN=H,VINR/2/3=0V,Total for All Channels	-	-	1.0	mA
Output OFF Current 2	I <sub>off2</sub>	OUTEN=L,VINR/2/3=0V,Total for All Channels	-	-	3.0	mA
Supply Voltage Alternation of Output Current 1	V <sub>c1</sub>	V <sub>cc</sub> =4.5 to 5.5V,VINR=0.8V,CHR only	-	10	15	%/V
Supply Voltage Alternation of Output Current 2	V <sub>c2</sub>	V <sub>cc</sub> =4.5 to 5.5V,OUTEN2or3=L,VINR=0.8V, VIN2/3=0.3V,CHR+CH2or3	-	10	15	%/V
Temperature coefficient of Output Current 1	T <sub>C1</sub>	VINR=0.8V,CHR only	-	-800	-	ppm/°C
Temperature coefficient of Output Current 2	T <sub>C2</sub>	OUTEN2or3=L,VINR=0.8V,VIN2/3=0.3V, CHR+CH2or3	-	-800	-	ppm/°C

\*1 The amplifier linearity is calculated using best fit method at three points. The output currents chosen 20mA, 40mA, and, 60mA. The transfer function for I<sub>out</sub> is defined as follows: I<sub>out</sub> = G<sub>i</sub>\*VIN + I<sub>os</sub>

●Laser Amp AC CHARACTERISTICS (Vcc=5.0, Ta=25°C unless otherwise specified)

PARAMETERS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Enable Time	Ten	ENABLE L→H 50% to Iout 50%, Iout=40mA	-	150	-	ns
Disable Time	Tdis	ENABLE H→L 50% to Iout 50%, Iout=40mA	-	20	-	ns
ON Time	Ton	OUTEN H→L 50% to Iout 50%, Iout=40mA+40mA	-	1	-	ns
OFF Time	Toff	OUTEN L→H 50% to Iout 50%, Iout=40mA+40mA	-	1	-	ns
Rise Time	Tr	CHR+CH2/3, Iout 10-90%, Iout=40mA+40mA	-	1	-	ns
Fall Time	Toff	CHR+CH2/3, Iout 10-90%, Iout=40mA+40mA	-	1	-	ns
Over Shoot	OS		-	5	-	%
Oscillator Frequency	fOSC	Rfreq=3.6kΩ	380	470	560	MHz
Oscillator Temperature Coefficient	TcOSC	Rfreq=3.6kΩ	-	-300	-	ppm/°C
Output Current Noise	Iono	Iout=40mA, CHR only	-	3.5	-	nA/√Hz

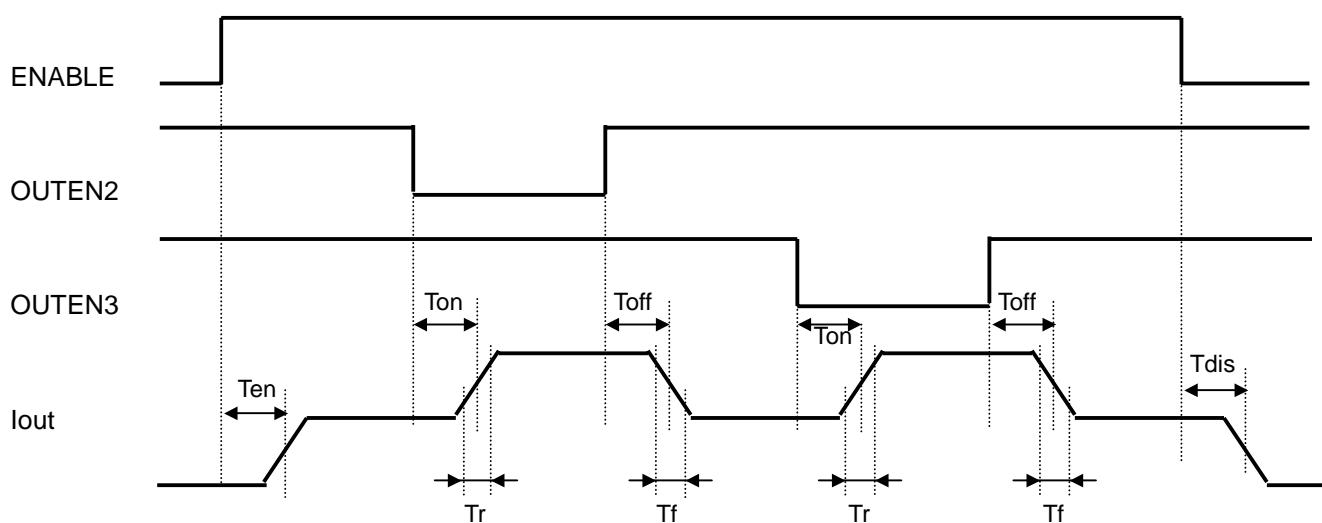
■Iout Control

ENABLE	OUTEN2	OUTEN3	Iout
L/OPEN	X	X	OFF
H	H/OPEN	H/OPEN	Iout=VINR*Gi1
H	L	H/OPEN	Iout=VINR*Gi1+VIN2*Gi2
H	H/OPEN	L	Iout=(VINR+VIN3)*Gi1
H	L	L	Iout=(VIN2+VIN3)*Gi1+VIN2*Gi2

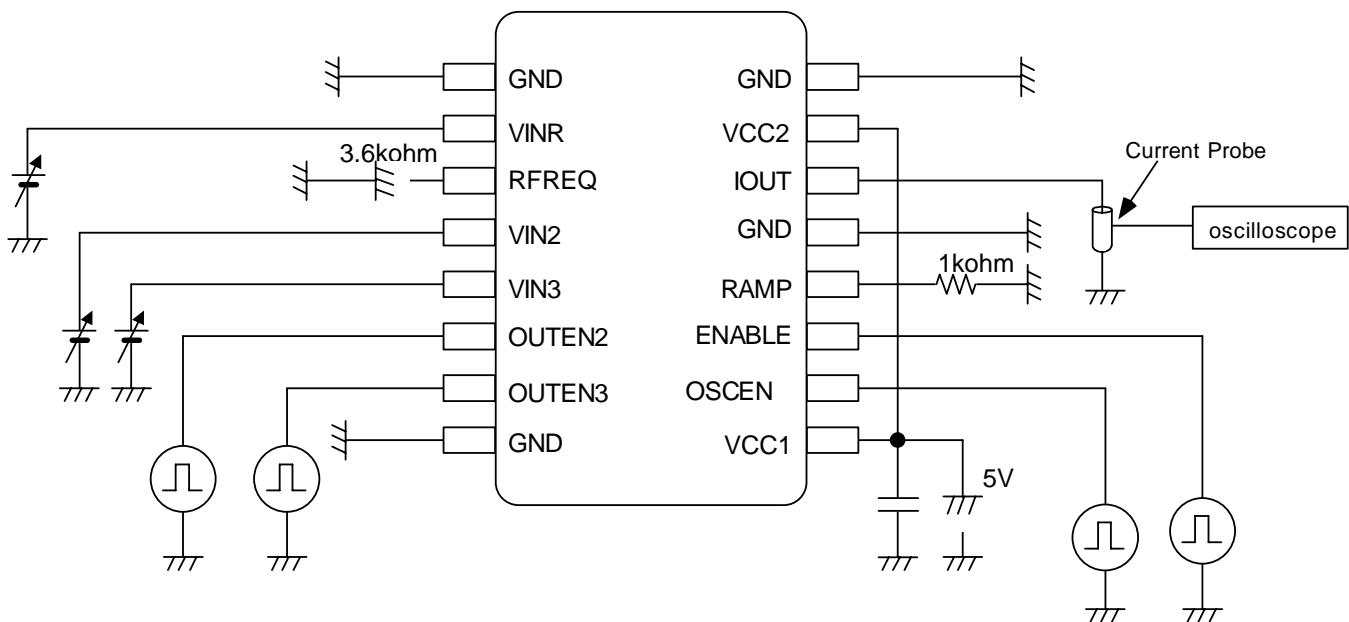
■Oscillator Control

ENABLE	OSCEN	OUTEN2	OUTEN3	OSCILLATOR
L/OPEN	X	X	X	OFF
H	L/OPEN	X	X	OFF
H	H	X	X	ON

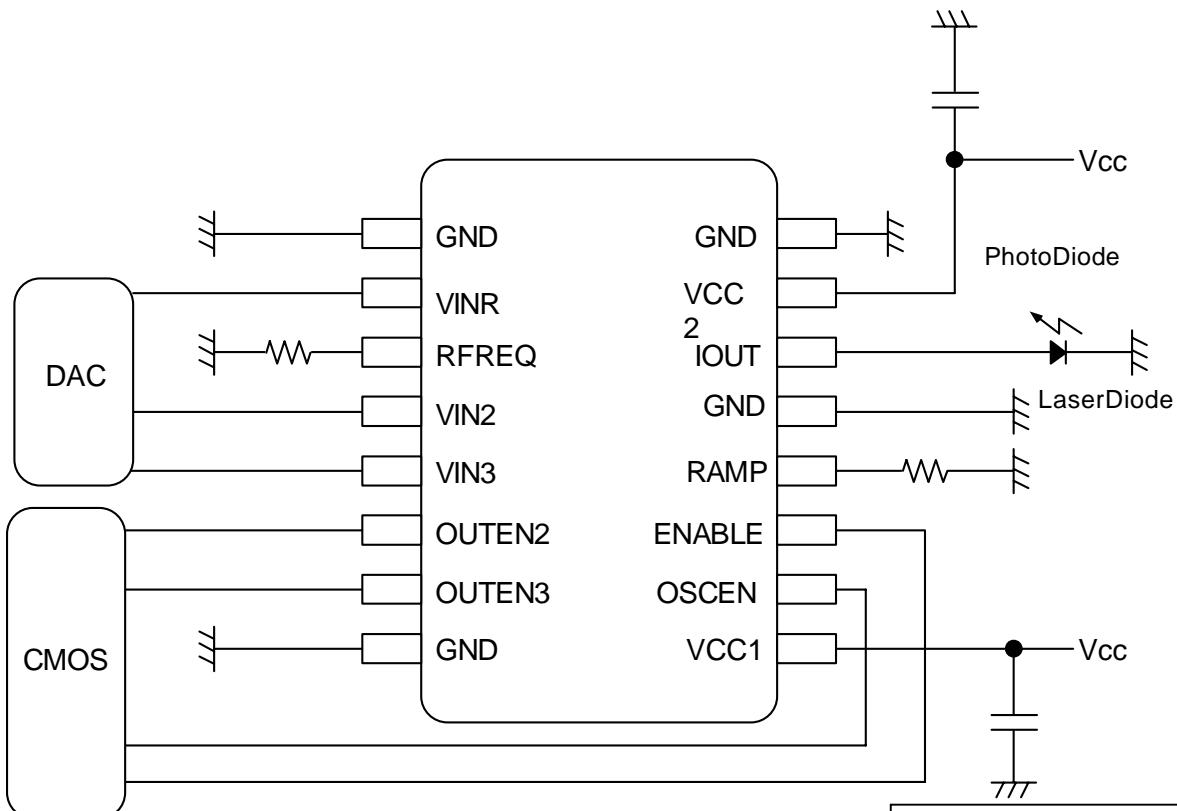
■Timing Diagram



## ■TEST CIRCUIT



## ■APPLICATION CIRCUIT



**[CAUTION]**  
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